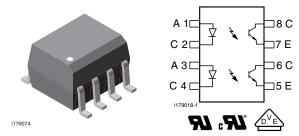
VOD205T, VOD206T, VOD207T, VOD211T, VOD213T, VOD217T

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Vishay Semiconductors

Optocoupler, Phototransistor Output, Dual Channel, SOIC-8 Package

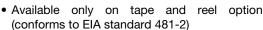


DESCRIPTION

The VOD205T, VOD206T, VOD207T, VOD211T, VOD213T, VOD217T are optically coupled pairs with a gallium arsenide infrared LED and a silicon NPN phototransistor. Signal information, including a DC level, can be transmitted by the device while maintaining a high degree of electrical isolation between input and output.

FEATURES

- Two channel coupler
- SOIC-8 surface mountable package
- Standard lead spacing of 0.05"





COMPLIANT

- Isolation test voltage, 4000 V_{RMS}
- Compatible with dual wave, vapor phase and IR reflow soldering
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

AGENCY APPROVALS

- UL1577, file no. E52744 system code Y
- cUL file no. E52744, equivalent to CSA bulletin 5A
- DIN EN 60747-5-5 (VDE 0884-5) approved, contact customer service if this option is required

ORDERING INFORMATIO	N							
v o [D 2	#	#	Ţ		DC-8		
	PART N	UMBER			6.	1 mm		
AGENCY CERTIFIED/PACKAGE		CTR (%)						
UL, cUL	40 to 80	63 to 125	100 to 200	> 20	> 100 ⁽¹⁾	> 100 ⁽²⁾		
SOIC-8	VOD205T	VOD206T	VOD207T	VOD211T	VOD213T	VOD217T		

Notes

 $^{(1)}$ $I_F = 10 \text{ mA}$

 $^{(2)}$ I_F = 1 mA

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
INPUT								
Peak reverse voltage		V_R	6	V				
Peak pulsed current	1 µs, 300 pps	I _{FM}	1	Α				
Continuous forward current per channel		I _F	30	mA				
Power dissipation		P _{diss}	50	mW				
Derate linearly from 25 °C			0.66	mW/°C				
OUTPUT								
Collector emitter breakdown voltage		BV _{CEO}	70	V				
Emitter collector breakdown voltage		BV _{ECO}	7	V				
Continuous output current		I _{Cmax} .	50	mA				
Power dissipation per channel		P _{diss}	125	mW				
Derate linearly from 25 °C			1.67	mW/°C				

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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT					
COUPLER									
Isolation test voltage	t = 1 s	V _{ISO}	4000	V _{RMS}					
Total package dissipation ambient (2 LEDs and 2 detectors, 2 channels)		P _{tot}	300	mW					
Derate linearly from 25 °C			4	mW/°C					
Storage temperature		T _{stg}	-40 to +150	°C					
Operating temperature		T _{amb}	-40 to +100	°C					
Soldering time from 260 °C ⁽¹⁾		T _{sld}	10	S					

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
 implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
 maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices.

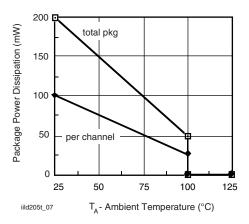


Fig. 1 - Power Dissipation vs. Ambient Temperature

ELECTRICAL CHARACTERISTCS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	I _F = 10 mA		V_{F}		1.2	1.55	V
Reverse current	V _R = 6 V		I _R		0.1	100	μΑ
Capacitance	$V_R = 0 V$		Co		25		pF
OUTPUT							
Collector emitter breakdown voltage	I _C = 100 μA		BV _{CEO}	70			V
Emitter collector breakdown voltage	I _E = 100 μA		BV _{ECO}	7			V
Collector emitter leakage current	V _{CE} = 10 V, I _F = 0 A		I _{CEO}		5	50	nA
Collector emitter capacitance	V _{CE} = 0 V		C _{CE}		10		pF
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 2.5 \text{ mA}$		V _{CEsat}			0.4	V
COUPLER							
Capacitance (input to output)			C _{IO}		0.5		pF

Note

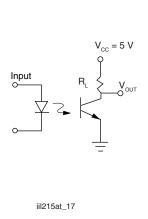
• Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

VOD205T, VOD206T, VOD207T, VOD211T, VOD213T, VOD217T

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CURRENT TRANSFER RATIO								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
		VOD205T	CTR _{DC}	40		80	%	
		VOD206T	CTR _{DC}	63		125	%	
	V _{CE} = 5 V, I _F = 10 mA	VOD207T	CTR _{DC}	100		200	%	
		VOD211T	CTR _{DC}	20			%	
I _C /I _F		VOD213T	CTR _{DC}	100			%	
		VOD205T	CTR _{DC}	13	30		%	
	\\	VOD206T	CTR _{DC}	22	45		%	
	$V_{CE} = 5 \text{ V}, I_{F} = 1 \text{ mA}$	VOD207T	CTR _{DC}	34	70		%	
		VOD217T	CTR _{DC}	100	120		%	

SWITCHING CHARACTERISTICS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Turn-on time	$I_{C} = 2 \text{ mA}, R_{L} = 100 \Omega, V_{CC} = 5 \text{ V}$	t _{on}		5		μs	
Turn-off time	$I_C = 2 \text{ mA}, R_L = 100 \Omega, V_{CC} = 5 \text{ V}$	t _{off}		4		μs	
Rise time	$I_C = 2 \text{ mA}, R_L = 100 \Omega, V_{CC} = 5 \text{ V}$	t _r		5		μs	
Fall time	$I_C = 2 \text{ mA}, R_L = 100 \Omega, V_{CC} = 5 \text{ V}$	t _f		4		μs	



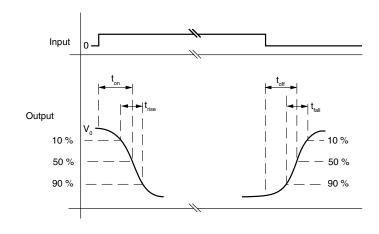
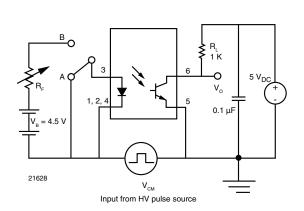


Fig. 2 - Switching Test Circuit

COMMON MODE TRANSIENT IMMUNITY								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Common mode transient immunity at logic high	$V_{CM} = 1000 V_{P-P}, R_L = 1 k\Omega,$ $I_F = 0 \text{ mA}$	C _{MH}		10 000		V/µs		
Common mode transient immunity at logic low	$V_{CM} = 1000 V_{P-P}, R_L = 1 k\Omega,$ $I_F = 10 \text{ mA}$	C _{ML}		10 000		V/µs		

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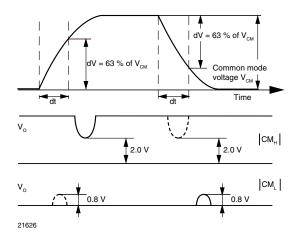


Fig. 3 - Test Circuit for Common Mode Transient Immunity

SAFETY AND INSULATION RATINGS									
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT			
Climatic classification	according to IEC 68 part 1			40/100/21					
Polution degree				2					
Comparative tracking index		CTI	175		399				
Peak transient overvoltage		V _{IOTM}	6000			V			
Peak insulation voltage		V _{IORM}	560			V			
Resistance (input to output)		R _{IO}		100		GΩ			
Apparent charge method a		q _{pd}				С			
Apparent charge method b		q _{pd}				С			
Safety rating - power output		P _{SO}			350	mW			
Safety rating - input current		I _{SI}			150	mA			
Safety rating - temperature		T _{SI}			165	°C			
External creepage distance			4			mm			
Internal creepage distance			4			mm			
External clearance distance		_	4			mm			
Insulation thickness			0.2			mm			

Note

• As per IEC 60747-5-5, §7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

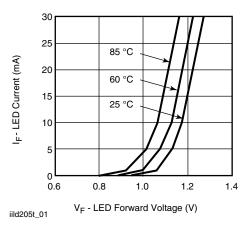


Fig. 4 - Forward Current vs. Forward Voltage

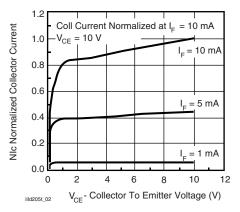


Fig. 5 - Collector Emitter Current vs. V_{CE}

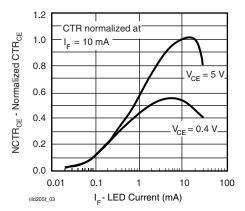


Fig. 6 - Normalized CTR_{CE} vs. Forward Current

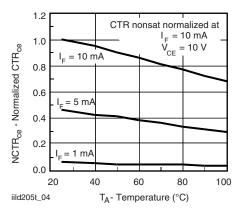


Fig. 7 - Current Transfer Ratio (normalized) vs.
Ambient Temperature

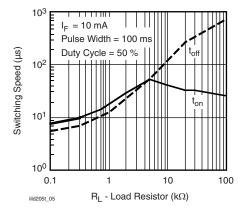


Fig. 8 - Switching Speed vs. Load Resistor

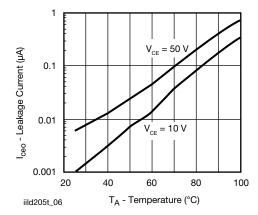
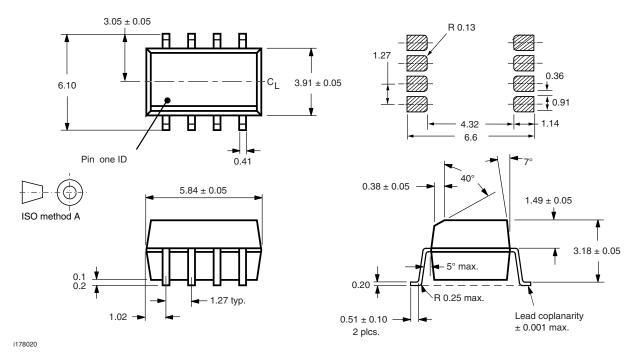


Fig. 9 - Collector Current vs. Ambient Temperature

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PACKAGE DIMENSIONS in millimeters



PACKAGE MARKING (example of VOD207T)



TAPE AND REEL PACKAGING

Dimensions in millimeters

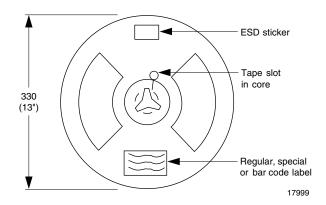


Fig. 10 - Tape and Reel Shipping Medium (EIA-481, revision A, and IEC 60286), 2000 units per reel

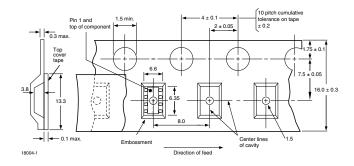


Fig. 11 - Tape Dimensions, 2000 Parts per Reel



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